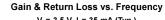
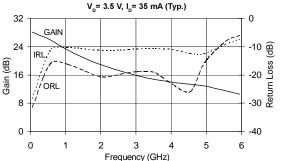


## **Product Description**

Sirenza Microdevices' SGA-3586 is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring 1 micron emitters provides high  $F_{\scriptscriptstyle T}$  and excellent thermal perfomance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. At 850 Mhz and 35mA , the SGA-3586 typically provides +24.9 dBm output IP3, 25dB of gain, and +13.5 dBm of 1dB compressed power using a single positive voltage supply. Only 2 DC-blocking capacitors, a bias resistor and an optional RF choke are required for operation.





## **SGA-3586**

# DC-5000 MHz Silicon Germanium Cascadeable Gain Block



## **Product Features**

• DC-5000 MHz Operation

Single Voltage Supply

• High Gain: 25 dB typ. at 850 MHz

Low Current Draw: 35mA at 3.5V typ.

• Low Noise Figure: 2.5 dB typ. at 1950 MHz

## **Applications**

• PA Driver Amplifier

• Cellular, PCS, GSM, UMTS

• IF Amplifier

· Wireless Data, Satellite

Symbol	Parameter	Units	Frequency	Min.	Тур.	Max.
G	Small Signal Gain	dB	850 MHz 1950 MHz 2400 MHz	22.5	25.0 19.7 18.3	27.5
P <sub>1dB</sub>	Output Power at 1dB Compression		850 MHz 1950 MHz		13.5 13.5	
OIP <sub>3</sub>	Output Third Order Intercept Point	dBm	850 MHz 1950 MHz		24.9 26.1	
Bandwidth	Determined by Return Loss (>10dB)	MHz			5000	
IRL	Input Return Loss	dB	1950 MHz		12.8	
ORL	Output Return Loss	dB	1950 MHz		19.0	
NF	Noise Figure	dB	1950 MHz		2.5	
V <sub>D</sub>	Device Operating Voltage	V		3.1	3.5	3.9
I <sub>D</sub>	Device Operating Current	mA		31	35	39
R <sub>TH</sub> , j-I	Thermal Resistance (junction to lead)	°C/W		·	97	

**Test Conditions:** 

 $V_s = 5 V$  $R_{sus} = 130 Ohms$  I<sub>D</sub> = 35 mA Typ. T₁ = 25°C OIP<sub>3</sub> Tone Spacing = 1 MHz, Pout per tone = -5 dBm  $Z_s = Z_t = 50$  Ohms

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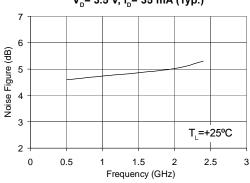
## Typical RF Performance at Key Operating Frequencies

			Frequency (MHz)					
Symbol	Parameter	Unit	100	500	850	1950	2400	3500
G	Small Signal Gain	dB	28.2	27.1	25.0	19.7	18.3	14.8
OIP <sub>3</sub>	Output Third Order Intercept Point	dBm		23.5	24.9	26.1	26.5	
P <sub>1dB</sub>	Output Power at 1dB Compression	dBm		13.3	13.5	13.5	13.2	
IRL	Input Return Loss	dB	28.4	12.8	10.7	10.5	11.1	10.6
ORL	Output Return Loss	dB	31.5	17.1	15.9	20.5	20.3	18.9
S <sub>12</sub>	Reverse Isolation	dB	29.4	29.0	28.1	24.1	22.4	19.2
NF	Noise Figure	dB		2.4	2.5	2.5	2.5	

**Test Conditions:** 

 $V_s = 8 V$  $R_{pias} = 130 Ohms$  I<sub>D</sub> = 35 mA Typ. T<sub>.</sub> = 25°C  $OIP_3$  Tone Spacing = 1 MHz, Pout per tone = -5 dBm  $Z_s = Z_1 = 50$  Ohms

## Noise Figure vs. Frequency $V_p = 3.5 \text{ V}, I_p = 35 \text{ mA (Typ.)}$



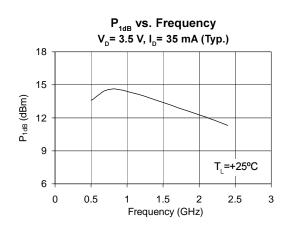
### OIP<sub>3</sub> vs. Frequency $V_D = 3.5 \text{ V}, I_D = 35 \text{ mA (Typ.)}$ 35 30 OIP<sub>3</sub> (dBm) 25 20 T,=+25°C 15 0 0.5 1.5 2 2.5 3 Frequency (GHz)

## **Absolute Maximum Ratings**

Parameter	Absolute Limit	
Max. Device Current (I <sub>D</sub> )	70 mA	
Max. Device Voltage (V <sub>D</sub> )	5 V	
Max. RF Input Power	+18 dBm	
Max. Junction Temp. (T <sub>J</sub> )	+150°C	
Operating Temp. Range (T <sub>L</sub> )	-40°C to +85°C	
Max. Storage Temp.	+150°C	

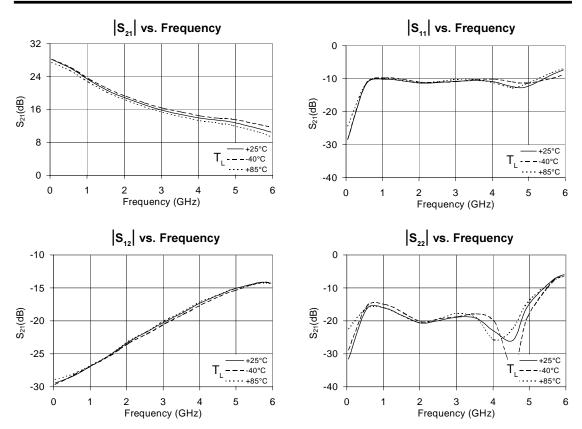
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias conditions should also satisfy the following expression:  $I_pV_p < (T_i - T_i) / R_{rut}$  j-I





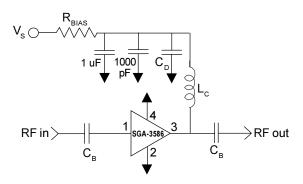
## Typical RF Performance Over Temperature ( Bias: $V_{\rm p}$ = 3.5 V, $I_{\rm p}$ = 35 mA (Typ.) )

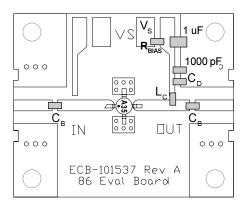


NOTE: Full S-parameter data available at www.sirenza.com



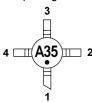
## **Basic Application Circuit**





#### Part Identification Marking

The part will be marked with an "A35" designator on the top surface of the package.



## Application Circuit Element Values

Reference		Fr	equency (N	(lhz)	
Designator	500	850	1950	2400	3500
C <sub>B</sub>	220 pF	100 pF	68 pF	56 pF	39 pF
C <sub>D</sub>	100 pF	68 pF	22 pF	22 pF	15 pF
L <sub>c</sub>	68 nH	33 nH	22 nH	18 nH	15 nH

Recommended Bias Resistor Values for $I_D$ =35mA $R_{BIAS}$ =( $V_S$ - $V_D$ ) / $I_D$				
Supply Voltage(V <sub>s</sub> )	5 V	8 V	10 V	12 V
R <sub>BIAS</sub> 75 Ω 130 Ω 180 Ω 240 Ω				
Note: R <sub>BIAS</sub> provides DC bias stability over temperature.				

#### **Mounting Instructions**

- 1. Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

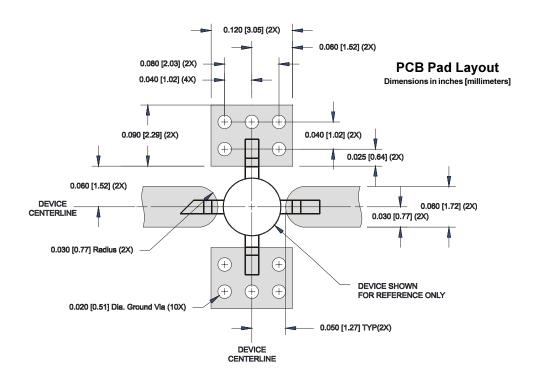
Pin#	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.

# Caution: ESD sensitive Appropriate precautions in handling, packaging and testing devices must be observed.

#### **Part Number Ordering Information**

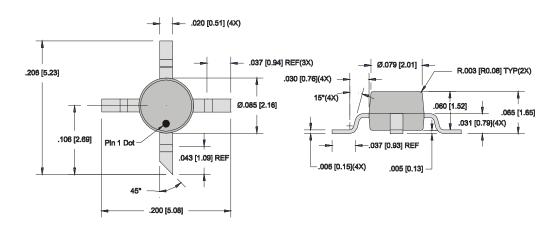
Part Number	Reel Size	Devices/Reel
SGA-3586	13"	3000





#### **Nominal Package Dimensions**

Dimensions in inches [millimeters]
Refer to drawing posted at www.sirenza.com for tolerances.



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EDS-101382 Rev B